

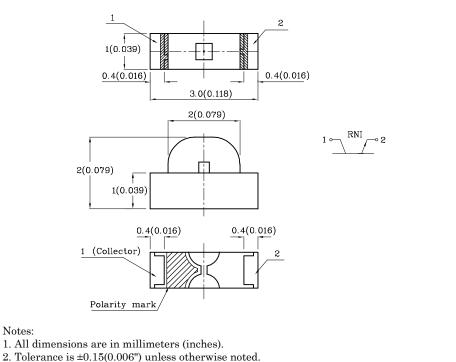
### Part Number: XZRNI56W

3.0 mm x 1.0 mm Right Angle Phototransistor

#### Features

- Long life and robust package
- Standard Package: 2,000pcs/ Reel
- MSL (Moisture Sensitivity Level): 3
- Halogen-free
- $\bullet$  RoHS compliant





Specifications are subject to change without notice.

**Package Schematics** 

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Condiction
VBR CEO	Collector-to-Emitter Breakdown Voltage	30	-	-	V	$\begin{split} I_{c} &= 100 \mu A \\ E_{e} &= 0 m W/cm^{2} \end{split}$
VBR ECO	Emitter-to-Collector Breakdown Voltage	5	-	-	V	$\begin{split} I_{\rm E} &= 100 \mu A \\ E_{\rm e} &= 0 {\rm mW/cm^2} \end{split}$
VCE(SAT)	Collector-to-Emitter Saturation Voltage	-	-	0.8	V	$\label{eq:lc} \begin{split} I_{C} &= 2mA\\ E_{e} &= 20mW/cm^{2} \end{split}$
Iceo	Collector Dark Current	-	-	100	nA	$\label{eq:Vce} \begin{split} V_{CE} &= 10V\\ E_e &= 0mW/cm^2 \end{split}$
TR	Rise Time (10% to 90%)	-	15	-	μs	$V_{\rm CE} = 5V$ $I_{\rm C} = 1mA$ $R_{\rm L} = 1K\Omega$
$\mathrm{T}\mathrm{F}$	Fall Time (90% to 10%)	-	15	-	μs	
I(ON)	On State Collector Current	0.2	0.4	-	mA	$\label{eq:Vce} \begin{split} V_{\rm ce} &= 5V\\ E_{\rm e} &= 1mW/cm^2\\ \lambda &= 940nm \end{split}$
$\lambda_{0.1}$	Range of spectral bandwidth	420	-	1120	nm	-
$\lambda_{ m p}$	Wavelength of peak Sensitivity	-	940	-	nm	-
201/2	Angle of half sensitivity	-	160	-	deg	-

Dec 07, 2020

XDSA7441 V7 Layout: Maggie L.



3.0 mm x 1.0 mm Right Angle Phototransistor

#### Absolute Maximum Ratings at TA=25°C

Parameter	Maximum Ratings				
Collector-to-Emitter Voltage	30V				
Emitter-to-Collector Voltage	5V				
Power Dissipation at (or below) 25°C Free Air Temperature	100mW				
Operating / Storage Temperature Range	$-40 \sim +85^{\circ}\mathrm{C}$				

A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

0.5

0.4

0.3

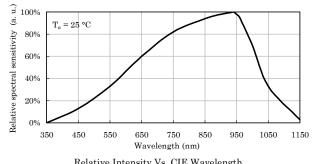
0.2

0.1

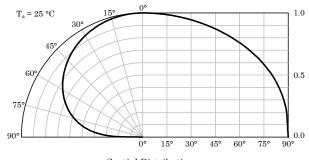
 $T_a \neq 25 \text{ °C}$ 

 $Ee = 1 mW/cm^2$ 

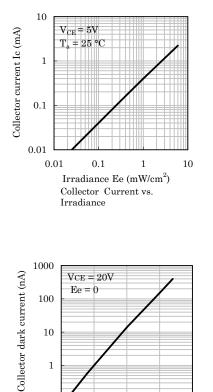
 $Ee = 0.5 mW/cm^2$ 

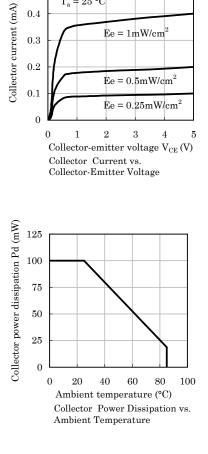


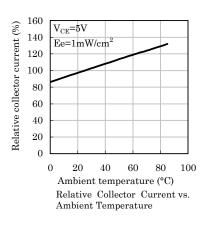
Relative Intensity Vs. CIE Wavelength

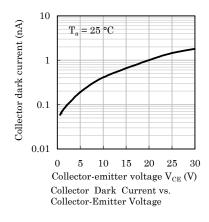












10

1

0.1

0

25

50

Ambient temperature (°C)

Collector Dark Current vs.

Ambient Temperature

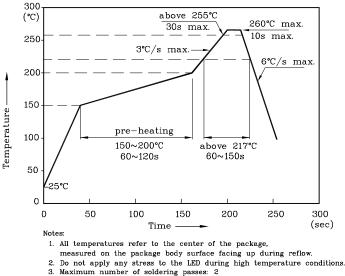
75

100



# ♦ LED is recommended for reflow soldering and soldering profile is shown below.

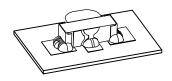
Reflow Soldering Profile for SMD Products (Pb-Free Components)



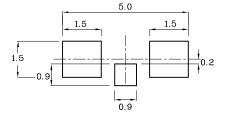
#### 3. Maximum number of soldering passes: 2

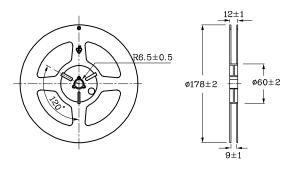
#### Reel Dimension (Units : mm)

✤ The device has a single mounting surface. The device must be mounted according to the specifications.

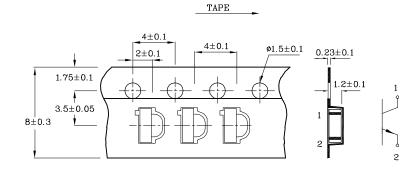


#### Recommended Soldering Pattern (Units : mm; Tolerance: ± 0.1)



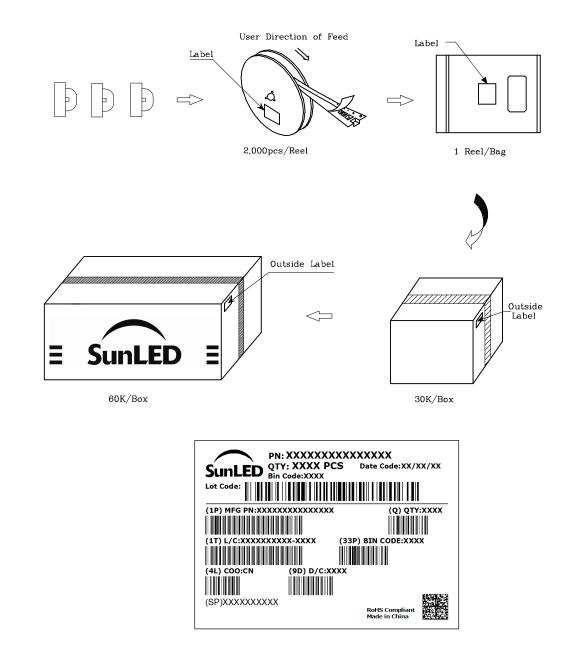


#### Tape Specification (Units : mm)





## PACKING & LABEL SPECIFICATIONS



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